

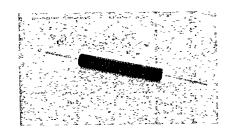
VARO SEMICONDUCTOR, INC., P.O. Box 469013 1000 N. Shiloh; Garland, Texas 75046-9013 (214) 271-8511 TWX 910-860-5178

T-23-05

June 1982

High Voltage Diode H1812

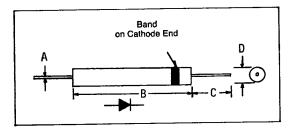
Designed for B & W TV High Voltage Rectifier up to 20 kVDC CRT Voltage
Avalanche Quality Rectifier Junctions
Molding Material Rated UL 94 V-O
Uniform Chip-to-Chip Recovery
Low RFI in TV Circuits
Platinum Doped



MAXIMUM RATINGS (At T _A = 25°C unless otherwise noted)	SYMBOL		UNITS
Repetitive Peak Reverse Voltage	V _{RRM}	30	- kV
Forward Current (Average) See Fig. 1, 2 & 3	I _{F(AV)}	600	μА
Forward Current (Total RMS)	I _{F(RMS)}	4.6	mA
Repetitive Peak Forward Current	I _{EBM}	100	mA
Storage Temperature Range	T _{STG}	-40 to +150	လ
Ambient Operating Temperature Range	TA	-40 to +100	°C

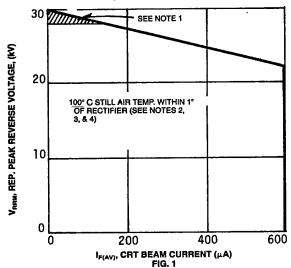
ELECTRICAL CHARACTERISTICS (At T₄ = 25°C unless otherwise noted)	SYMBOL		UNITS
Maximum Reverse Current at V _B =30kV	I _R	1	μА
Maximum Forward Voltage Drop at I _F =5mA	V _{FM}	85	v
Reverse Recovery Time, $I_F = 2mA$, $I_R = -4mA$ and I_{rr} (rec) = -1 mA (Fig. 4)	t _{rr}	100 typical 175 Max.	nsec
Soldering Temperature: 260°C Max. for 10 sec. max. 1/16" from epoxy			

Encapsulating Considerations: See Varo Application Note "Design Considerations for HV Silicon Rectifiers Integrated into Flyback Transformers."



LTR	INCHES	MILLIMETERS	
Α	.0236 Dia.	0.6 Dia.	
I в I	1.5	38,10	
С	.50 Min.	12,7 Min	
	.235	5,97	

DERATING FOR USE AS HIGH VOLTAGE RECTIFIER IN 15,734 Hz DEFLECTION SYSTEM



- 1) Operation in cross-hatched region should be limited to less than 5 min.
- less than 5 min.

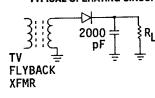
 2) Air temp, measured with calibrated laboratory-grade alcohol thermometer.

 3) Case temp. = 110°C when rectifier is operating at 22 kV V_{RRM}, 600 μA, in 95°C still air ambient.
 Case temp. measured with Tempil "Templiaq" Temp. indicating Liquid.
 Source: Tempil Division
 Big Three Industries, Inc.
 South Plainfield NJ 07080

 4) All temperatures presented here are approx. 10°C below

- 4) All temperatures presented here are approx. 10°C below known thermal runaway points. We recommend that customers intentionally raise the still air ambient temp on their designs to learn the actual thermal runaway point for their application. The final design should have at least 20°C early testor.

TYPICAL OPERATING CIRCUIT



TYPICAL APPLIED VOLTAGE

FIG. 2B

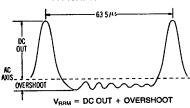
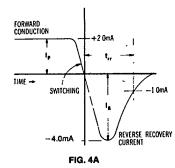


FIG. 2A

RECOVERY WAVEFORM



RECOVERY TEST CIRCUIT

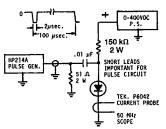
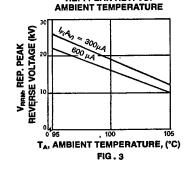


FIG. 4B



REP. PEAK REV. VS:

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